

NEW CM75YE13-12F MITSUBISHI IGBT MODULE

Model	CM75YE13-12F
Brand	mitsubishi
Category	MITSUBISHI
Collector-Emitter Voltage (Vces)	1200 V
Nominal Collector Current (Ic)	75 A
Collector-Emitter Sat. Voltage (Vce(sat))	2.10 V (max)
Diode Forward Voltage (Vf)	2.20 V (max)
Total Power Loss (Pt)	260 W (max)
Isolation Voltage (Visol)	2500 Vrms
Turn-off Time (toff)	0.35 μs (typ)
Gate-Emitter Voltage (Vges)	±20 V (max)
Thermal Resistance (Junction-Case)	0.50 °C/W (max)
Module Configuration	6-in-1

Note:

Invshop recommends that you inquire with the original factory or its agents about the latest production status and technical information about CM75YE13-12F. The product parameters displayed on Invshop are entered by Invshop engineers according to the specifications, and efforts have been made to minimize errors, but we cannot guarantee the complete correctness of the parameters. Please refer to the specification sheet!

